

### JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

# **TO-220-3L Plastic-Encapsulate Transistors**

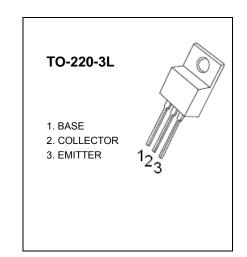
**2SD880** TRANSISTOR (NPN)

#### **FEATURES**

- Low Frequency Power Amplifier
- Complement to 2SB834

#### **MAXIMUM RATINGS** (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
Ic	Collector Current -Continuous	3	Α	
Pc	Collector Power Dissipation	1.5	W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55-150	$^{\circ}$	



**ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)** 

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100μA, I <sub>E</sub> =0	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I <sub>C</sub> =50mA, I <sub>B</sub> =0	60			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub> I <sub>E</sub> = 100μA, I <sub>C</sub> =0		7			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =60V, I <sub>E</sub> =0			100	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =7V, I <sub>C</sub> =0			100	μΑ
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	60		300	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> =3A, I <sub>B</sub> =300mA			1	V
Base-emitter voltage	$V_{BE}$	I <sub>C</sub> =0.5A, V <sub>CE</sub> = 5V			1	V
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =5 V, I <sub>C</sub> =500mA		3		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		70		pF
Turn on time	t <sub>on</sub>	- I <sub>B1</sub> =-I <sub>B2</sub> =0.2A, I <sub>C</sub> =2A - V <sub>CC</sub> =30V, PW=20μs		0.8		μs
Storage time	t s			1.5		μs
Fall time	t <sub>f</sub>			0.8		μs

#### **CLASSIFICATION OF hFE**

Rank	0	Υ	GR
Range	60-120	100-200	150-300

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